

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	21	(commom same share unique one individual single) near3 (cell semiconductor wafer element unit) near3 semiconductor near3 (MR magnetoresistive)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 08:53
L2	105889	(commom same share unique one individual single) near3 (cell semiconductor wafer element unit) near3 semiconductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 08:56
L3	1766705	(commom same share unique one individual single) near3 (cell semiconductor wafer element unit) near3 semiconductor ( integral\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 08:57
L4	1766705	(commom same share unique one individual single) near3 (cell semiconductor wafer element unit) near3 semiconductor ( integral\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 08:57
L5	458	(commom same share unique one individual single) near3 (cell semiconductor wafer element unit) near3 semiconductor near3 ( integral\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 08:57
L6	12167817	5 nea3 (plurality array multipl\$5 many several three four pair two)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 08:58
L7	431	5 and (plurality array many several three four pair two)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 08:59
L8	208	5 same (plurality array many several three four pair two)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 08:59

L9	2	8 and (mr magnetoresi\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/29 09:00
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